

# isc N-Channel MOSFET Transistor

## IXTP110N055P

#### FEATURES

- Static drain-source on-resistance: R<sub>D</sub>s(on) ≤13.5mΩ
- Fully characterized avalanche voltage and current
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



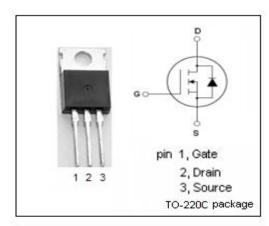
- DC/DC Converter
- · Ideal for high-frequency switching and synchronous rectification

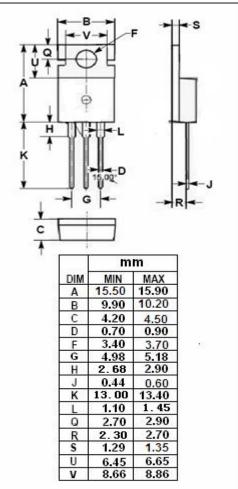
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	55	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-Continuous	110	А
I <sub>DM</sub>	Drain Current-Single Pulsed	250	А
$P_D$	Total Dissipation @T <sub>C</sub> =25℃	330	W
Tj	Operating Junction Temperature	-55~175	${\mathbb C}$
T <sub>stg</sub>	Storage Temperature	-55~150	°C

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{\text{th(j-c)}}$	Junction-to-case thermal resistance	0.45	°C/W







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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; ID =250 μ A	55		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; ID =250 μ A	2.5	5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =55A		13.5	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> =0V		±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 55V; V <sub>GS</sub> = 0V		25	- μ <b>Α</b>
		V <sub>DS</sub> = 55V; V <sub>GS</sub> = 0V;T <sub>J</sub> =125°C		250	
Vsp	Diode forward voltage	I <sub>F</sub> = 110A; V <sub>GS</sub> = 0V		1.5	V



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